PCN Number: 201)190917001.1A				PCN Date:		Jan. 9, 2020		
Title: Die Coating mate					change for Sele	ect Devices					
Cus	stomer	Contact:		PCI	<u> Manager</u>		Dept:		Qua	ity Services	
Proposed 1 st Ship Date:					18, 2019	Estimated Availabilit		le		Date provided at sample request.	
Change Type:											
	Assem	bly Site			Assembly Process				Assembly Materials		
	Design	า			Electrical Specification				Mechar	ical Specification	
	Test S	ite		Packing/Shipping/Labeling			g		Test Pr	ocess	
Wafer Bump Site					Wafer Bump Material				Wafer E	Bump Process	
☐ Wafer Fab Site					Wafer Fab Materials				Wafer I	ab Process	
					Part number change						
	_	•			DCN		-			•	

PCN Details

Description of Change:

Revision A is to announce the <u>addition</u> of new devices that were not included on the original PCN notification. These new devices are included below as the Group 2 device list and in the device list on page 2 above. The expected first shipment date for these new devices will be 90 days from this notice for these newly added devices only.

This notification is to announce the change to the Die Coating material for the selected devices listed in "Product Affected" section.

Die coating material differences (on top of top thick copper metal layer) are noted below:

Group 1 Devices:

Change From	Change To
NONE	POLYIMIDE
Die Revision: A	Die Revision: D*

Group 2 Devices:

Change From	Change To
NONE	POLYIMIDE
Die Revision: A	Die Revision: B*

^{*}No design change. Addition of Polyimide die coating only.

Qual details are provided in the Qual Data Section.

Reason for Change:

Quality Improvement

Anticipated impact on Form, Fit, Function, Quality or Reliability (positive / negative):

None

Changes to product identification resulting from this PCN:

The Die Rev designator will change as shown in the table and sample label below:

	Current	New
Device Group	Die Rev [2P]	Die Rev [2P]
1	Α	D
2	А	В

Sample product shipping label (not actual product label)

TEXAS INSTRUMENTS MADE IN: Malaysia 2DC: 2Q:

(1P) SN74LS07NSR (Q) 2000 (D) 0336 (31T)LOT: 3959047MLA (4W) TKY(1T) 7523483S12

(2P) REV: (20L) 630: SHE (22L) AS0: MLA

(V) 0033317 (21L) CCO:USA (23L) ACO: MYS

OPT: ITEM:

(L)T0:3750 LBL:

MSL 2 /260C/1 YEAR SEAL DT MSL 1 /235C/UNLIM 03/29/04

Product Affected Group:

Group 1 Devices:

UCC27201ADPRR UCC27201ADPRT UCC27201ADRCR UCC27201ADRCT

Group 2 Devices:

UCC27517ADBVR UCC27517ADBVT UCC27517DBVR UCC27517DBVT

Group 1 Device Qual memo:

Qualification Report

UCC27201A die with Polyimide coating (PI) Approve Date 12-Jun-2019

Qualification Results Data Displayed as: Number of lots / Total sample size / Total failed

Туре	Test Name / Condition	Duration	Qual Device: UCC27201ADP R	Qual Device: UCC27201ADR C	QBS Product Reference: UCC27201ADP R	QBS Product Reference: UCC27201ADR CT	QBS Process Reference: UCC27201AQD DARQ1	QBS Process & Package Reference: UCC27201AQD MKRQ1	QBS Package Reference: TPA5050RSA	QBS Package Reference: TPS61020DRC CU WIRE
AC	Autoclave 121C	96 Hours	-	-	3/231/0	3/231/0	3/231/0	3/231/0	-	3/231/0
CDM	ESD - CDM - Q100	1500 Volts	-	-	-	-	1/3/0	1/3/0	-	-
CDM	ESD CDM	+/- 250, 500V	-	-	1/3/0	1/3/0	-	-	-	-
DS	Die Shear	-	1/Pass	1/Pass	1/Pass	1/Pass	1/Pass	1/Pass	1/10/0	3/30/0
ED	Electrical Characterization	Per Datasheet Parameters	-	-	1/Pass	1/Pass	3/90/0	3/90/0	-	-
ELFR	Early Life Failure Rate, 125C	48 Hours	-	-	-	-	3/2400/0	-	-	-
HAS T	Biased HAST, 130C/85%RH	96 Hours	-	-	-	-	3/231/0	3/231/0	1/80/0	-
нвм	ESD - HBM - Q100	1000 Volts	-	-	-	-	1/3/0	1/3/0	-	-
HTO L	Life Test, 125C	1000 Hours	-	-	-	-	3/231/0	1/77/0	-	-
HTO L	Life Test, 140C	480 Hours	-	-	-	-	-	-	1/116/0	-
HTSL	High Temp Storage Bake 150C	1000 Hours	-	-	-	-	1/45/0	1/77/0	-	-
HTSL	High Temp Storage Bake 170C	420 Hours	-	-	-	-	-	-	-	3/231/0
LU	Latch-up	(per AEC- Q100-004)	-	-	-	-	1/6/0	1/6/0	-	-

Туре	Test Name / Condition	Duration	Qual Device: <u>UCC27201ADP</u> <u>R</u>	Qual Device: <u>UCC27201ADR</u> <u>C</u>	QBS Product Reference: UCC27201ADP R	QBS Product Reference: UCC27201ADR CT	QBS Process Reference: UCC27201AQD DARQ1	QBS Process & Package Reference: UCC27201AQD MKRQ1	QBS Package Reference: TPA5050RSA	QBS Package Reference: TPS61020DRC CU WIRE
PD	Physical Dimensions		-	-	-	-	-	3/30/0	1/5/0	3/15/0
PTC	Power Temperature Cycle, -40/125C	1000 Cycles	-	-	-	-	1/45/0	-	-	-
TC	Temperature Cycle, -65/150C	1000 Cycles	-	-	-	-	-	-	-	3/231/0
TC	Temperature Cycle, -65/150C	500 Cycles	-	-	3/231/0	3/231/0	3/231/0	3/231/0	-	3/261/0
TC- BP	Post TC Bond Pull	Wires	-	-	-	-	1/30/0	3/15/0	-	-
TS	Thermal Shock - 65/150C	1000 Cycles	-	-	-	-	-	-	-	3/231/0
TS	Thermal Shock - 65/150C	500 Cycles	-	-	-	-	-	-	-	3/231/0
WBP	Bond Pull	Wires	1/Pass	1/Pass	1/Pass	1/Pass	1/40/0	3/90/0	1/76/0	3/228/0
WBS	Bond Shear	Wires	1/Pass	1/Pass	1/Pass	1/Pass	1/40/0	3/90/0	1/76/0	3/228/0
YLD	Yield Evaluation	(per mfg. Site specification)	1/Pass	1/Pass	-	-	-	-	1/Pass	3/Pass

⁻ Preconditioning was performed for Autoclave, Unbiased HAST, THB/Biased HAST, Temperature Cycle, Thermal Shock, and HTSL, as applicable

- The following are equivalent HTOL options based on an activation energy of 0.7eV: 125C/1k Hours, 140C/480 Hours, 150C/300 Hours, and 155C/240 Hours The following are equivalent HTSL options based on an activation energy of 0.7eV: 150C/1k Hours, and 170C/420 Hours The following are equivalent Temp Cycle options per JESD47: -55C/125C/700 Cycles and -65C/150C/500 Cycles
- Quality and Environmental data is available at TI's external Web site: http://www.ti.com/

Green/Pb-free Status: Qualified Pb-Free (SMT) and Green

Group 2 Device Qual memo:



TIInformation Selective Disclosure

Automotive New Product Qualification Summary (As per AEC-Q100 and JEDEC Guidelines)

UCC27517AQDBVRQ1 with PI

Qualification Results Data Displayed as: Number of lots / Total sample size / Total failed

+						Data Displaye	a as. Hambe	i oi iota / Total samp	ore size / Total Talle	u		
	Туре	#	Test Spec	Min Lot Qty	SS/Lot	Test Name / Condition	Duration	Qual Device: UCC27517AQDBVRQ1	QBS Product Reference: UCC27519AQDBVRQ1	QBS Process Reference: TP\$2543QRTE	QBS Package Reference: OPA356AQDBVRQ1	QBS Package Reference: TPS61085ATDGKRQ1
	Test Group A – Accelerated Environment Stress Tests											
	HAST	A2	JEDEC JESD22- A110	3	77	Biased HAST 130C/85%RH	96 Hours	-	1/77/0	3/231/0	3/231/0	-
	UHAST			-	•	Unbiased HAST 130C/85%RH	96 Hours	-	-	-	1/77/0	-
	AC	А3	JEDEC JESD22- A102	3	77	Autoclave 121C	96 Hours	-	1/80/0	3/237/0	3/231/0	1/77/0
	TC	Α4	JEDEC JESD22- A104 and Appendix 3	3	77	Temperature Cycle, -65/150C	500 Cycles	1/77/0	1/77/0	3/231/0	3/231/0	1/77/0
	TC-BP	Α4	MIL-STD883 Method 2011	1	60	Post Temp. Cycle Bond Pull	500 Cycles	1/5/0	1/5/0	1/5/0	1/5/0	-
	PTC	A5	JEDEC JESD22- A105	1	45	Power Temperature Cycle, -40/125C	1000 Cycles	N/A	-	1/50/0	-	-
	HTSL	A6	JEDEC JESD22- A103	1	45	High Temp Storage Bake 175C	500 Hours	-	1/45/0	3/145/0	1/45/0	-
	Test Group B – Accelerated Lifetime Simulation Tests											
	HTOL	B1	JEDEC JESD22- A108	3	77	Life Test, 125C	1000 Hours	-	1/80/0	-	3/231/0	-
	HTOL	B1	JEDEC JESD22- A108	3	77	Life Test, 150C	408 Hours	-	-	3/231/0	-	-

Туре	#	Test Spec	Min Lot Qty	SS/Lot	Test Name / Condition	Duration	Qual Device: UCC27517AQDBVRQ1	QBS Product Reference: UCC27519AQDBVRQ1	QBS Process Reference: TPS2543QRTE	QBS Package Reference: OPA356AQDBVRQ1	QBS Package Reference: TPS61085ATDGKRQ1
ELFR	B2	AEC Q100- 008	3	800	Early Life Failure Rate, 125C	48 Hours	-	-	-	3/2400/0	-
ELFR	B2	AEC Q100- 008	o	800	Early Life Failure Rate, 150C	24 Hours	ı	-	3/2400/0	-	-
EDR	В3	AEC Q100- 005	3	77	NVM Endurance, Data Retention, and Operational Life	-	N/A	-	-	-	-
		Test Group C -	- Packa	ge Assen	ibly Integrity Tests						
WBS	C1	AEC Q100- 001	1	30	Wire Bond Shear (Cpk>1.67)	-	1/30/0	-	1/30/0	-	-
WBP	C2	MIL-STD883 Method 2011	1	30	Bond Pull	76 Wires, 3 units min	1/76/0	-	-	-	-
WBP	C2	MIL-STD883 Method 2011	1	30	Wire Bond Pull (Cpk>1.67)	-	-	-	-	-	-
SD	СЗ	JEDEC JESD22- B102	1	15	Surface Mount Solderability	Pb Free and SnPb	-	1/30/0	1/30/0	-	1/30/0
PD	C4	JEDEC JESD22- B100 and B108	3	10	Physical Dimensions	Cpk>1.67	1/30/0	-	3/90/0	-	-
		Test Group D	- Die F	abricatio	n Reliability Tests						
EM	D1	JESD61	•	•	Electromigration	-	Completed Per Process Technology Requirements	-	-	-	-
TDDB	D2	JESD35	1	ı	Time Dependant Dielectric Breakdown	-	Completed Per Process Technology Requirements	-	1	-	-
HCI	D3	JESD60 & 28	1	1	Hot Injection Carrier	-	Completed Per Process Technology Requirements	-	1	-	-
NBTI	D4	-	1	1	Negative Bias Temperature Instability	-	Completed Per Process Technology Requirements	-	-	-	-
SM	D5	-	1	ı	Stress Migration	•	Completed Per Process Technology Requirements	-	-	-	-
			E – Ele	ctrical Ve	rification Tests						
НВМ	E2	AEC Q100- 002	1	3	ESD - HBM - Q100	4000 V	1/3/0	-	1/3/0	-	-
CDM	E3	AEC Q100- 011	1	3	ESD - CDM - Q100	1500 V	1/3/0	1/3/0	1/3/0	-	-
LU	E4	AEC Q100-	1	6	Auto Latch-up	(Per AEC	-	-	1/6/0	-	Taylo RE: G

	Туре	#	Test Spec	Min Lot Qty	SS/Lot	Test Name / Condition	Duration	Qual Device: UCC27517AQDBVRQ1	QBS Product Reference: UCC27519AQDBVRQ1	QBS Process Reference: TP\$2543QRTE	QBS Package Reference: OPA356AQDBVRQ1	QBS Package Reference: TPS61085ATDGKRQ1
Г			004				Q100-004)					
	LU	E4	AEC Q100- 004	1	6	Auto Latch-up	Ta(max)	1/6/0	-	-	-	-
	LU	E4	AEC Q100- 004	1	6	Latch-up	(per JESD78)	-	1/6/0	-	1/6/0	-
	ED	E5	AEC Q100- 009	3	30	Auto Electrical Distributions	Cpk>1.67 Room, hot, and cold test	3/90/0	3/90/0	3/90/0	1/90/0	1/30/0

A1 (PC): Preconditioning: Performed for THB, Biased HAST, AC, uHAST, TC & PTC samples, as applicable.

Ambient Operating Temperature by Automotive Grade Level: Grade 0 (or E): -40° C to $+150^{\circ}$ C Grade 1 (or Q): -40° C to $+125^{\circ}$ C Grade 2 (or T): -40° C to $+105^{\circ}$ C Grade 3 (or I): -40° C to $+85^{\circ}$ C

E1 (TEST): Electrical test temperatures of Qual samples (High temperature according to Grade level): Room/Hot/Cold: HTOL, ED Room/Hot: THB / HAST, TC / PTC, HTSL, ELFR, ESD & LU Room: AC/JHAST

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